

# 2.0 A Single-Phase Glass Passivated Bridge Rectifiers Rectifier Reverse Voltage 50 to 1000V

DB-S



### **Features**

- This series is UL listed under the Recognized Component Index, file number E142814
- The plastic material used carries Underwriters Laboratory flammability recognition 94V-0
- Surge overload ratings to 50 amperes
- Ideal for printed circuit board application
- High temperature soldering guaranteed 265 °C /10 seconds at 5 lbs (2.3kg) tension

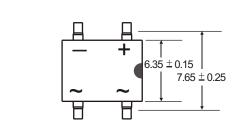
## **Mechanical Data**

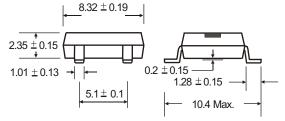
Case: Molded plastic

Terminals: Plated leads solderable per MIL-STD-202,

Method 208 Polarity: Marked on body Mounting Position: Any

Weight: 0.04 ounce, 1.0 grams (approx)





Dimensions in millimeters (1mm =0.0394")

**Maximum Ratings & Thermal Characteristics**Rating at 25 °C ambient temperature unless otherwise specified, Resistive or Inductive load, 60 Hz. For Capacitive load derate current by 20%.

Parameter	Symbol	DB201S	DB202S	DB203S	DB204S	DB205S	DB206S	DB207S	unit
Maximum repetitive peak reverse voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS bridge input voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	V
Maximum average forward rectified output current at TA=40°C	IF(AV)	2.0							А
Peak forward surge current single sine-wave superimposed on rated load (JEDEC Method)	IFSM	50							А
Rating for fusing ( t<8.3ms)	l <sup>2</sup> t	10							A <sup>2</sup> sec
Typical thermal resistance per element (1)	ReJA	110							°C / V
Typical junction capacitance per element (2)	Cj	25.0							pF
Operating junction and storage temperature range	TJ, TSTG	-55 to + 150							°C

### **Electrical Characteristics**

Rating at 25°C ambient temperature unless otherwise specified. Resistive or Inductive load, 60Hz. For Capacitive load derate by 20 %.

Parameter	Symbol	DB201S	DB202S	DB203S	DB204S	DB205S	DB206S	DB207S	Unit
Maximum instantaneous forward voltage drop per leg at 2.0A	VF	1.1						V	
Maximum DC reverse current at rated TA =25°C DC blocking voltage per element TA =125°C	IR	10 500						μΑ	

Notes: (1)Thermal resistance from Junction to Ambemt on P.C.board mounting. (2) Measured at 2.0 MHz and applied reverse voltage of 4.0 volts.

# Rating and Characteristic Curves (TA=25°C Unless otherwise noted) DB201S thru DB207S

Fig. 1 Derating Curve for Output Rectified Current

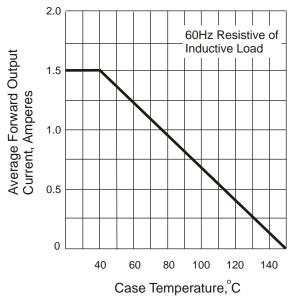


Fig. 3 Typical Instantaneous Forward Characteristics

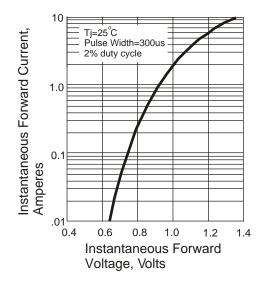


Fig. 2 Maximum Non-repetitive Peak Forward Surge Current

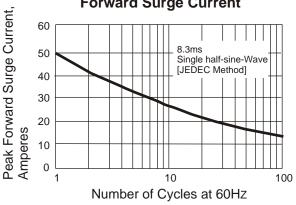


Fig. 4 Typical Revers Characteristics

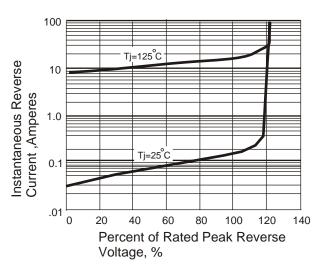
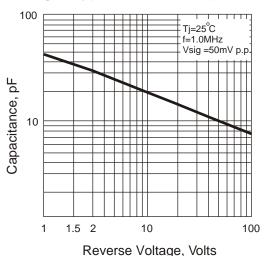


Fig. 5 Typical Junction Capacitance



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